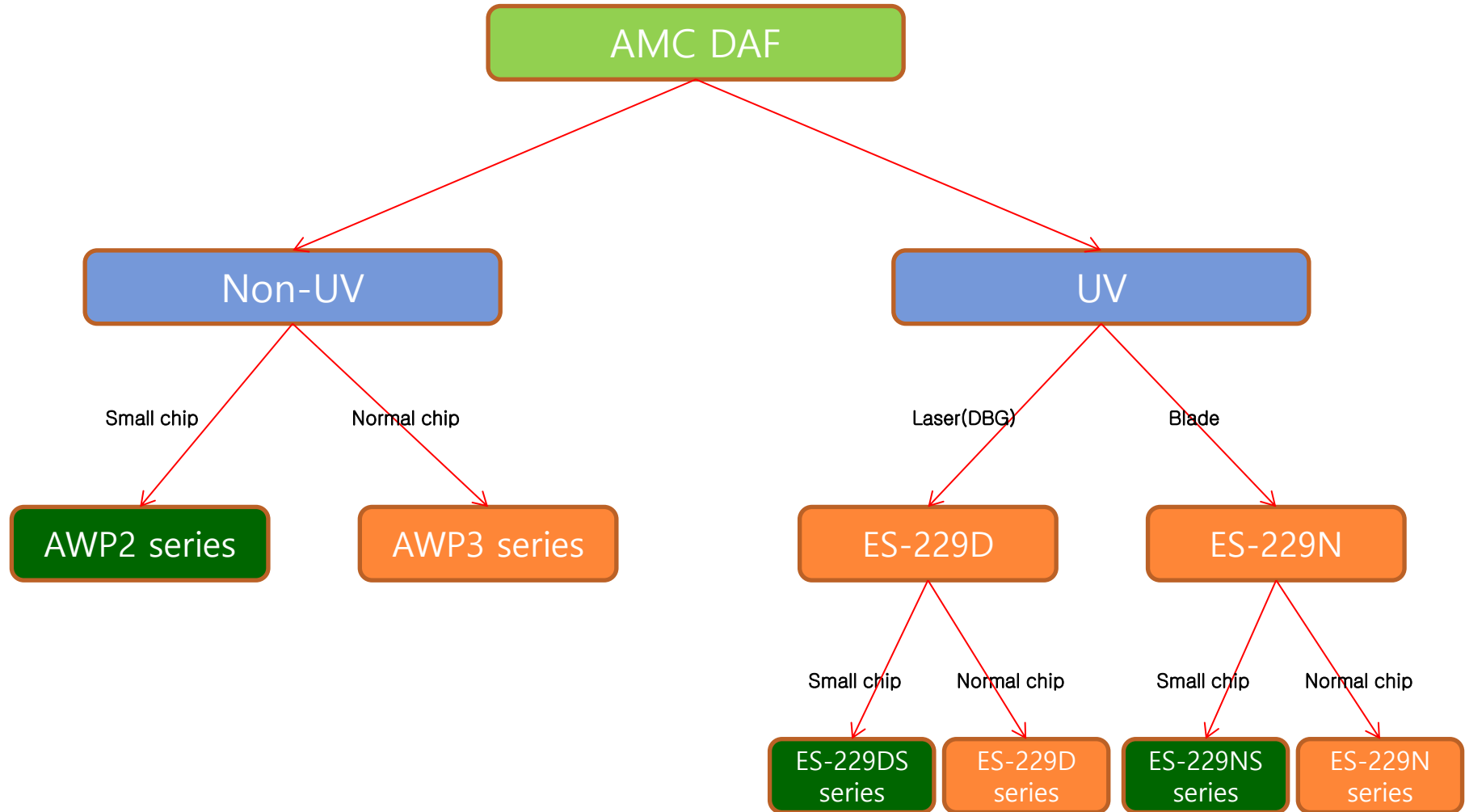


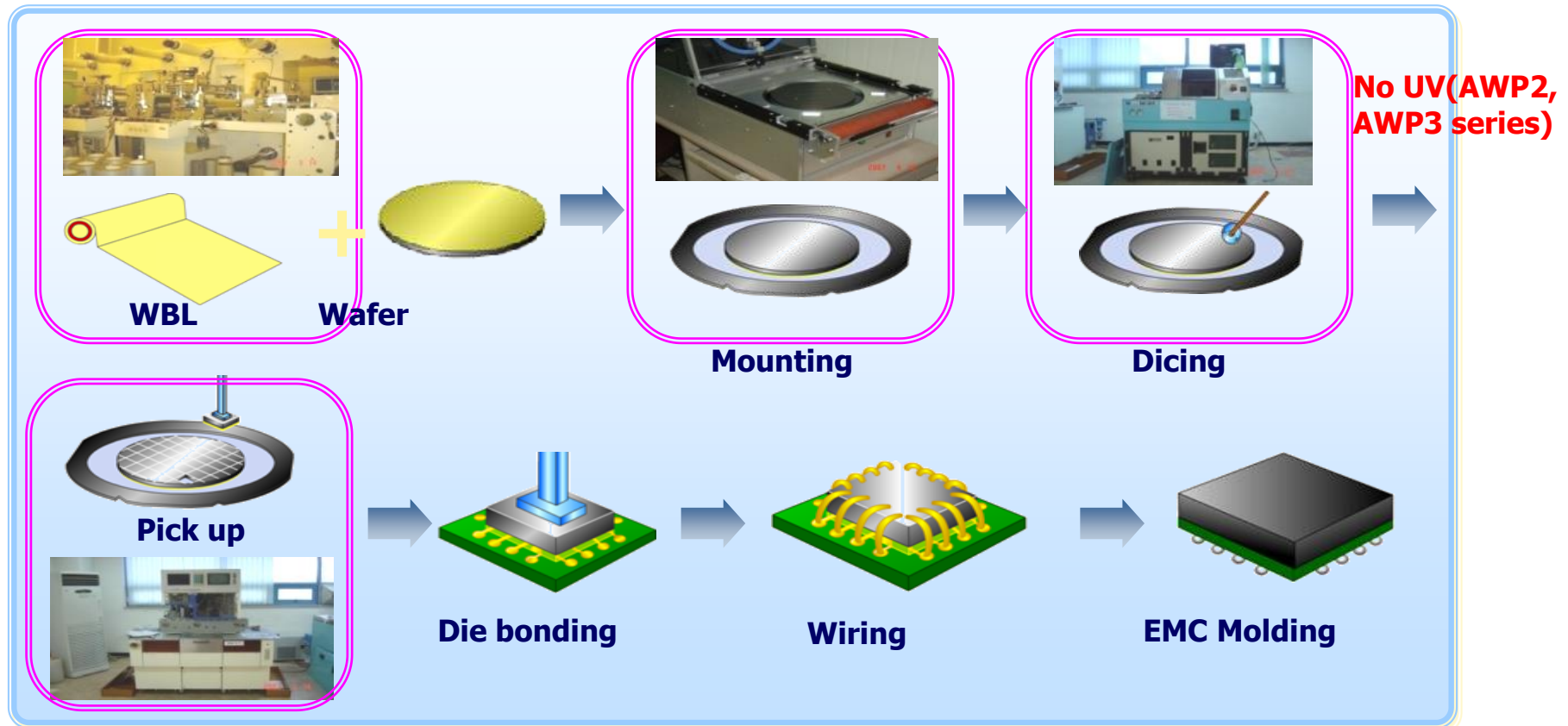
DAF(Die Attach Film) Introduction





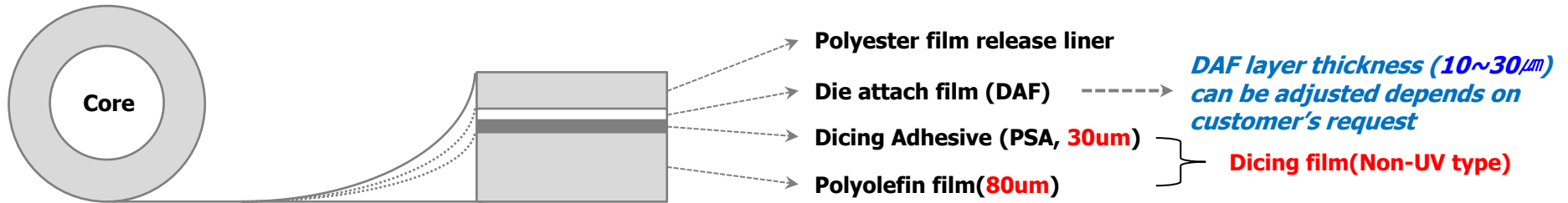
Non-UV type(Dicing film)

Through AWP2, AWP3 series(Non-UV DAF) application, semiconductor packaging companies can get a 1-step process(UV process) reducing benefit.

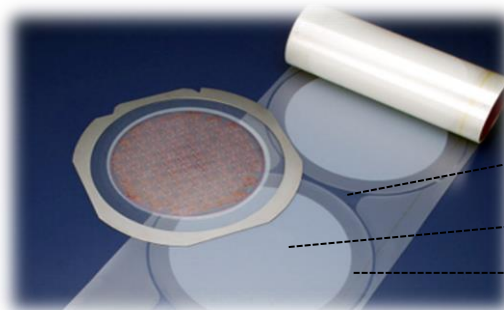
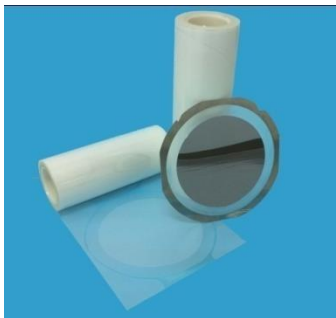


DAF is consist of 4 layers including die attach film(DAF) layer.
And DAF layer has circle shape to fit for ring frame and wafer attachment.

DAF Structure

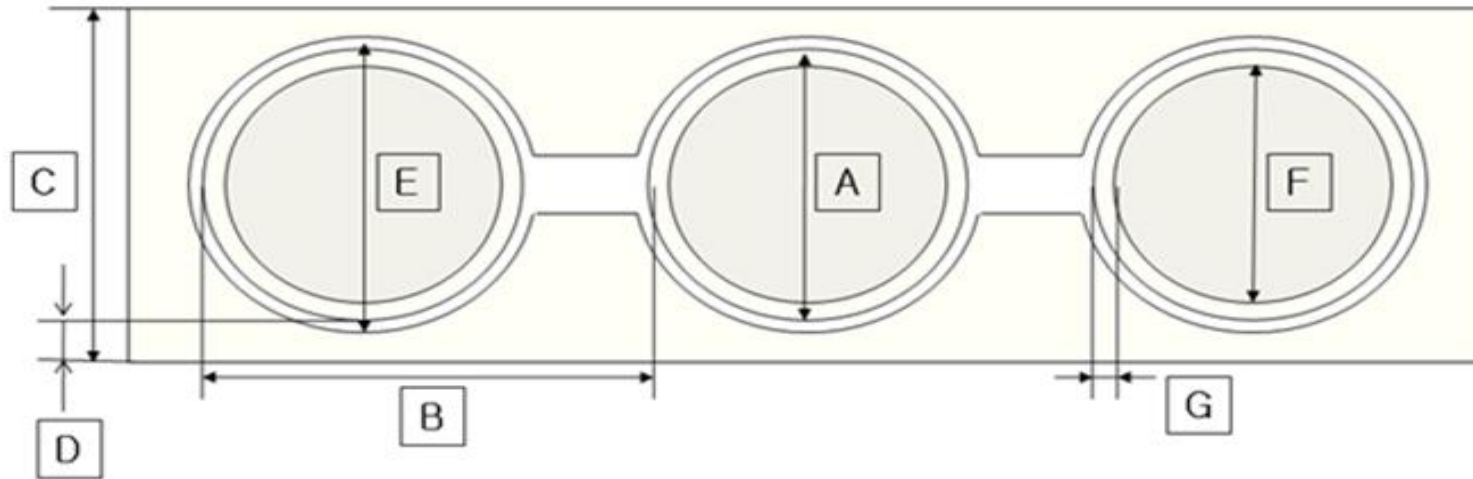


DAF Shape



- Polyester film release liner
- Die attach film (DAF)
- Polyolefin film + Dicing Adhesive (PSA)

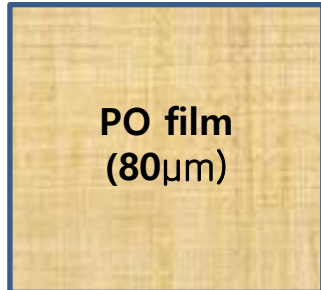
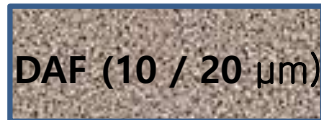
**AMC guarantees below specification and actual test result shows stable performance.
And Pre-cut size can be adjusted depends on customer's request.**



(Unit: μm)

	A	B	C	D	E	F	G
8 inch	270 \pm 1	279.5 \pm 1.5	290 \pm 2	10 \pm 2	277 \pm 1	220 \pm 1	25 \pm 5
12 inch	370 \pm 1	378.5 \pm 1.5	390 \pm 2	10 \pm 2	377 \pm 1	320 \pm 1	25 \pm 5

AMC checks and controls other properties even though not included in specification.



Properties			Unit	AWP2	AWP3
Modulus (DMA)	After Full cure	50 ~ 300°C	Mpa	354.5(@150°C) 214.4(@250°C)	8.44(@150°C) 6.35(@250°C)
Die Shear Strength	Full Cure	@R.T	Mpa	9.3	39.5
		@260°C	Mpa	4.8	11.7
CTE		α 1	ppm	58.4	213
		α 2	ppm	170.1	259.7
DSC Data	Before cure	On-set Temp	°C	176.7	189.3
		Delta H	J/g	45	38.79
Tg(DMA)	After Full cure	Tg	°C	200.2	239.3
Tensile properties	Adhesive layer	5% Modulus(MD)	MPa	9.54	4.67
		Elongation(MD)	%	26	268
	Dicing Tape	5% Modulus(MD)	MPa	5.03	
		5% Modulus(TD)	MPa	4.83	
		Elongation(MD)	%	636	
		Elongation(TD)	%	545	
180° Peel Strength	WBL Tape (DAF-Dicing)	Before UV	N/25mm	0.25	
	WBL-Wafer	Mount 60°C/70°C	N/25mm	0.72 / 1.08	0.76 / 1.14
Water Absorption	under 85°C/85%	after 24hr	wt%	0.75	0.86

Application

AWP2 series : under die size 3*3mm

AWP3 series : over die size 3*3mm

√ Test Product Model

Dummy wafer

√ Test Parameter

Spindle RPM		Feed Speed	Blade Height	Dicing Blade	Cut Method	Die size
Z1	45,000	30 mm/s	90um	ZH05-SD3500-N1-CC	Full Cut	5mm×5mm

√ Test Image



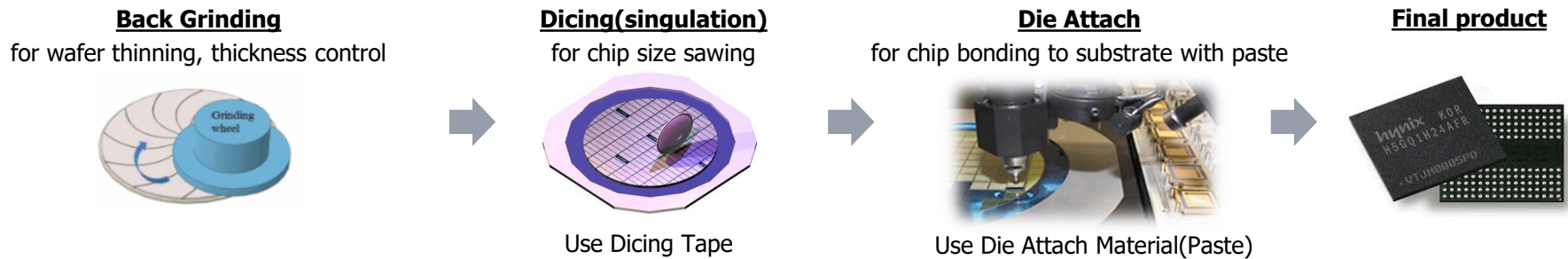
√ Pick-up height(um)

Sample	AWP3 series	H 社	D 社
Pick-up	400	500	600

UV type(Dicing film)

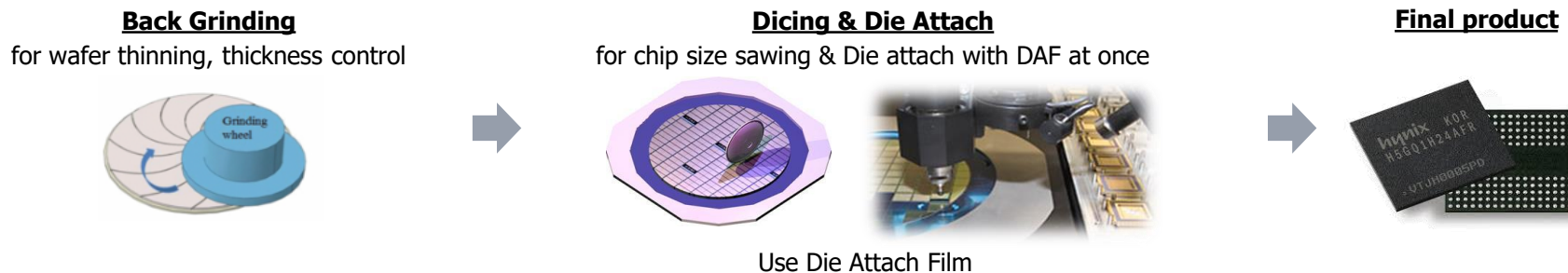
Through DAF application, semiconductor packaging companies can get a 1-step process reducing benefit and overcome the weakness(※) of paste attach process.

Conventional(Paste) Process



Reduce process from 2 steps to 1 step

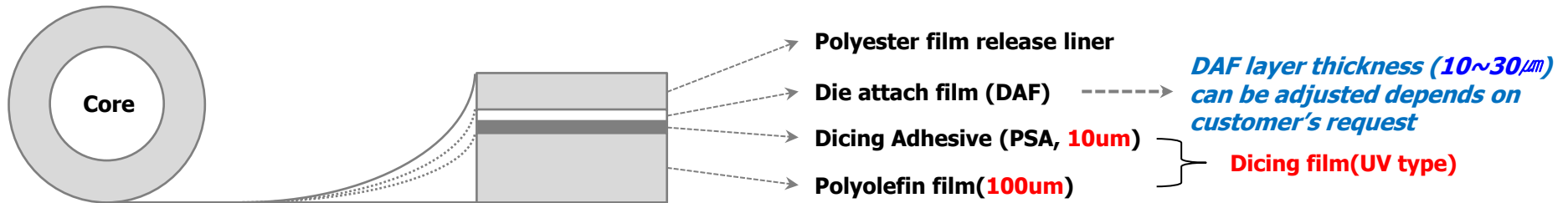
DAF Process



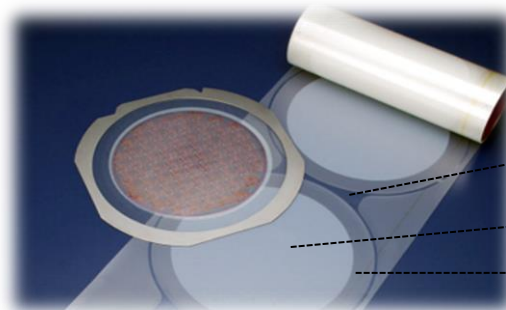
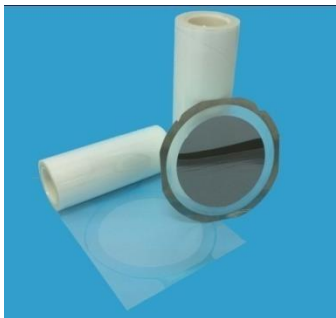
DAF is consist of 4 layers including die attach film(DAF) layer.

And DAF layer has circle shape to fit for ring frame and wafer attachment.

DAF Structure



DAF Shape



- Polyester film release liner
- Die attach film (DAF)
- Polyolefin film + Dicing Adhesive (PSA)

AMC guarantees below specification and actual test result shows stable performance. Especially AMC can control DAF layer thickness uniformity.

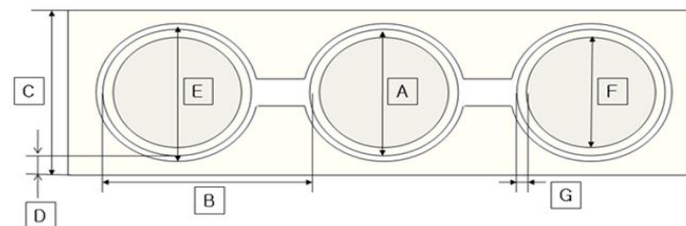
PET
Protective
film (38 μ m)

DAF (10 / 20 μ m)

PSA (10 μ m)

PO film
(100 μ m)

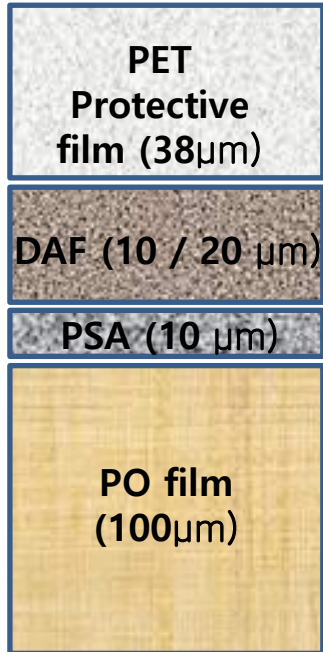
Characteristic		Spec	Unit	Comment
Roll width Size		390 \pm 2	mm	For 12 inch wafer
		290 \pm 2	mm	For 8 inch wafer
Sheets / roll		200	sheet	Can be decided according to customer's request
Thickness of Dicing Film		110 \pm 7	μ m	Polyolefin Film(100 μ m) + Dicing Layer (10 μ m)
Thickness of DAF layer		10 \pm 2	μ m	DAF layer only Actual manufacturing under \pm1μm range
Thickness of Dicing Die Attach Film		120 \pm 10	μ m	DAF layer + Dicing layer + Polyolefin Film
Dicing Film/DAF Peel Strength	before UV	110 \pm 50	gf/25mm	Peel strength between Dicing & DAF layer
	after UV	\leq 20	gf/25mm	
Adhesion strength		\geq 500	N/m	-
Tg(after curing)		\geq 150	$^{\circ}$ C	-
Dicing film elongation		MD : 600 \pm 200 TD : 900 \pm 200	%	-



(Unit: μ m)

	A	B	C	D	E	F	G
8 inch	270 \pm 1	279.5 \pm 1.5	290 \pm 2	10 \pm 2	277 \pm 1	220 \pm 1	25 \pm 5
12 inch	370 \pm 1	378.5 \pm 1.5	390 \pm 2	10 \pm 2	377 \pm 1	320 \pm 1	25 \pm 5

AMC checks and controls other properties even though not included in specification.

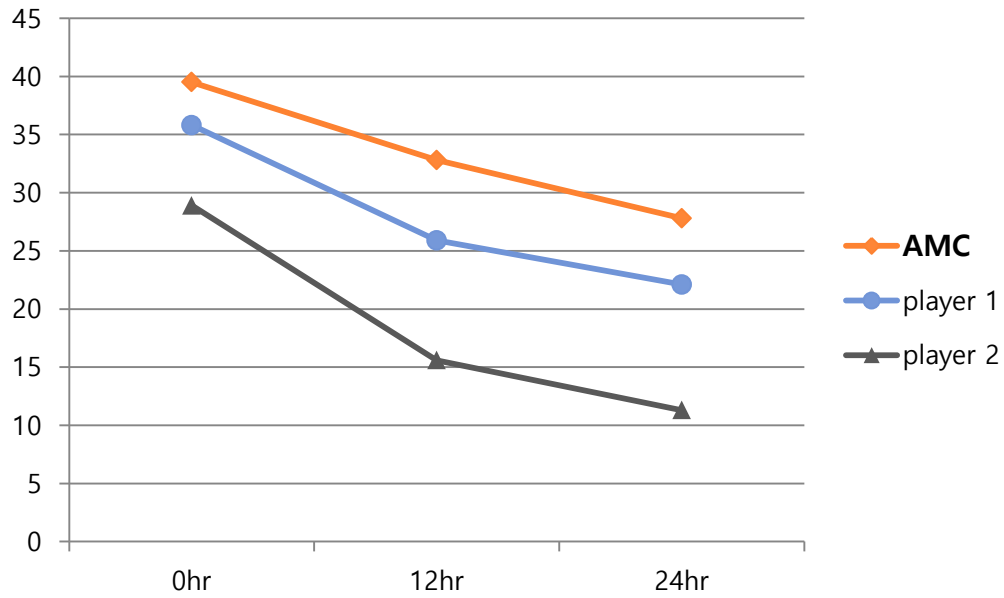


Properties		Unit	Result
Modulus (DMA)	Non Cure	Room temp. ~200°C	88.2(@150°C)
	After Full cure		8.44(@150°C) 6.35(@250°C)
Die Shear Strength	After Pre cure 30 min. @135°C	@180°C	Mpa 3.55
	Full Cure + After MRT (0, 12, 24h)	@R.T	Mpa 39.5 / 32.8 / 27.8
		@260°C	Mpa 11.7 / 12.4 / 11.6
CTE(TMA)	α 1	ppm	213
	α 2	ppm	259.7
DSC Data	Before cure	On-set Temp	°C 189.3
		Delta H	J/g 38.79
Tg(DMA)	After Full cure	Tg	°C 239.3
Tensile properties	Adhesive layer	5% Modulus(MD)	MPa 4.67
		Elongation(MD)	% 268
	Dicing Tape	5% Modulus(MD)	MPa 6.8
		5% Modulus(TD)	MPa 5.5
		Elongation(MD)	% 684
		Elongation(TD)	% 754
180° Peel Strength	WBL Tape (DAF-Dicing)	Before UV	gf/25mm 113.4
		After UV cure	gf/25mm 12.9
	WBL-Wafer	Mount 60°C/70°C	N/25mm 0.76/1.14
Water Absorption	under 85°C/85%	after 24hr	wt% 0.86
VOC 1 hr @150°C			wt% 0.71
Ionic impurities	CI	ppm	8.25

Compared with other DAF player's Die Shear Strength reliability in harsh condition(MRT(*)), AMC product shows the best performance.

10 μ m DAF layer Die Shear Strength comparison test

(*) MRT : Moisture Resistance Test (85°C, 85% moisture condition during 24hr)



(Unit: Mpa)

	ES-229D,N Series	Player 1	Player 2
0hr	39.5	35.8	28.9
12hr	32.8	25.9	15.6
24hr	27.8	22.1	11.3

(*) Player 1, 2 : Korean major domestic players

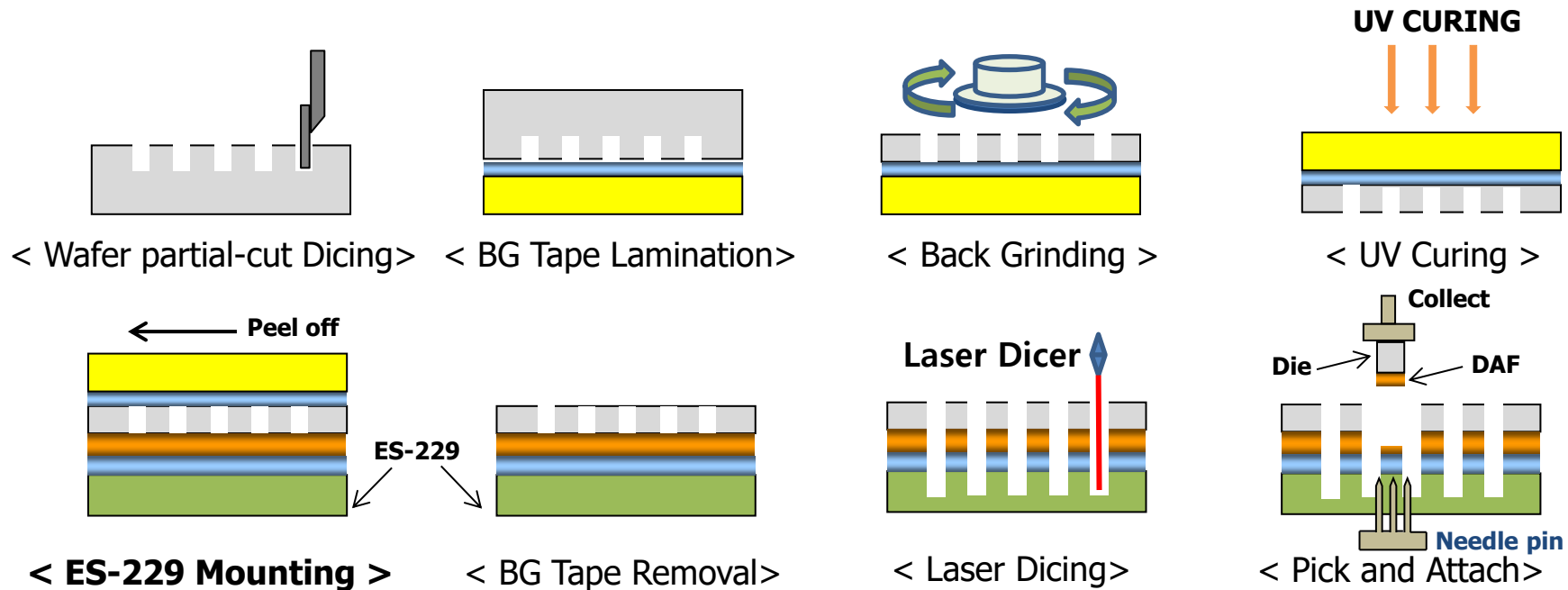
AMC can offer proper product according to customers' process type and required DAF layer thickness.

DAF Product Line

Series	Product	Applicable Process
ES-229D Series	ES-229D-10 (~30)	DBG(Dicing Before Grinding) & SDBG(Stealth DBG) Process
ES-229N Series	ES-229N-10 (~30)	Normal & DBG Process

- **DAF layer thickness can be adjusted by customers' request.**
 - **10 / 15 / 20 / 25 / 30 μm DAF layer**
- **According to customers' process type, AMC can suggest suitable product.**
 - **For normal blade dicing process**
 - **For DBG/SDBG sawing process**

ES-229 Series is suitable for not only thin die but also DBG PKG Process(Ultra-thin Die PKG Process) requiring laser dicing process



This process is as a kind of ultra-thin die fabrication process, it needs laser dicing process when DAF is diced during fabrication process. In this case, ES-229 also shows excellent pick-up workability as well as laser dicing of thin die.

√ Test Product Model

Dummy wafer


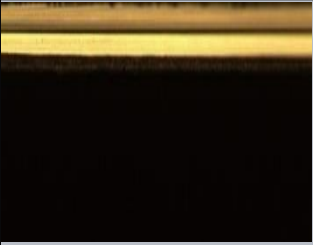

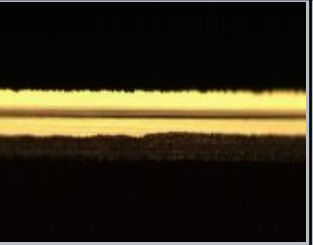

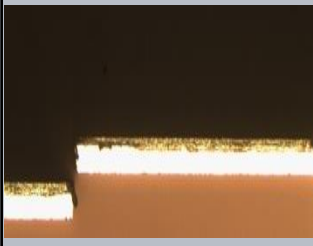

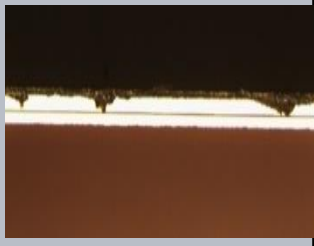
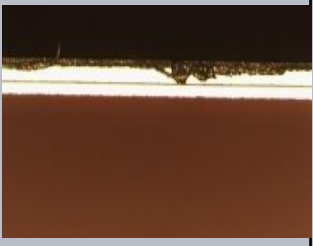
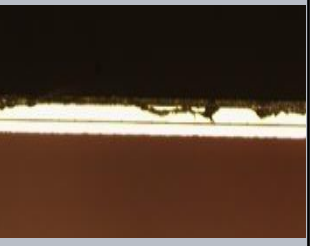
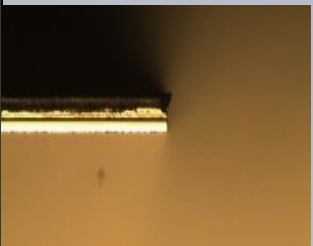



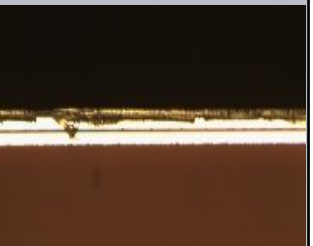
√ Test Parameter

Spindle RPM		Feed Speed	Blade Height	Dicing Blade	Cut Method
Z1	45,000	50 mm/s	155um	ZH05-SD3500-N1-CC	Step Cut
Z2	45,000	50 mm/s	70um	ZH05-SD3500-N1-BB	

√ Test Result

Sample	Wafer Thick.	Corner burr(%)	Side burr(%)	Bleed(%)
ES-229N-20	60um	1.6	14.1	15.6
Competitor A (Model A)	60um	23.8	88.1	76.2
Competitor A (Model B)	60um	17.5	67.5	97.5

√ Test Image

	1	2	3	4	5
ES-229N-20					
Competitor A (Model A)					
Competitor A (Model B)					

Test condition : After UV

√ Test Product Model

Dummy wafer

√ Test Parameter




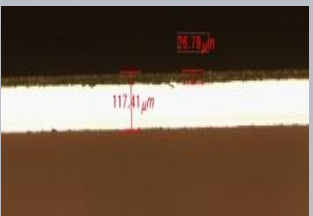
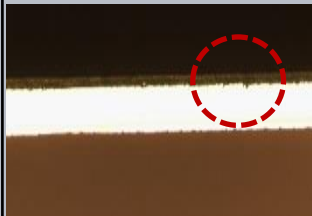


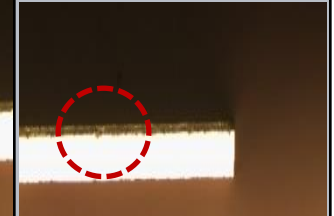

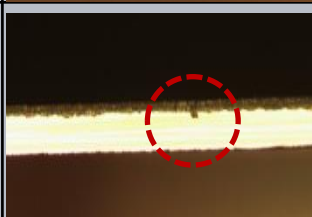



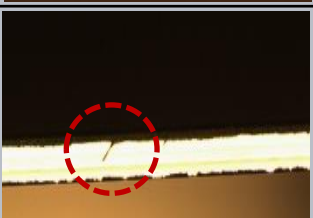
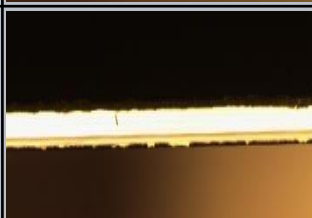



Spindle RPM		Feed Speed	Blade Height	Dicing Blade	Cut Method
Z1	45,000	50 mm/s	155um	ZH05-SD3500-N1-CC	Step Cut
Z2	45,000	50 mm/s	70um	ZH05-SD3500-N1-BB	

√ Test Result

Sample	Wafer Thick.	Corner burr(%)	Side burr(%)	Bleed(%)
ES-229N-20	90um	0.0	5.1	1.7
Competitor A (Model A)	90um	0.0	25.8	10.3
Competitor A (Model B)	90um	22.4	31.0	36.2
Competitor B	90um	3.4	29.3	18.9

√ Test Image

Test condition : After UV

	1	2	3	4	5
ES-229N-20					
Competitor A (Model A)					
Competitor A (Model B)					
Competitor B					

√ Test Product Model

Patten wafer


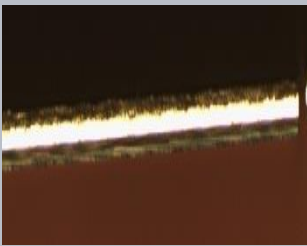
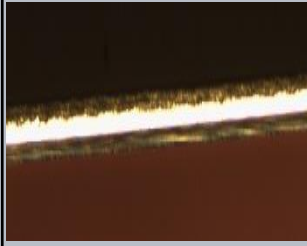
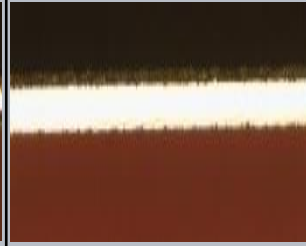

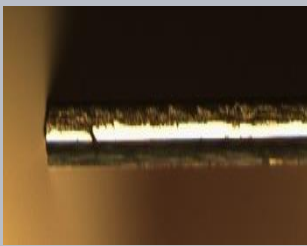
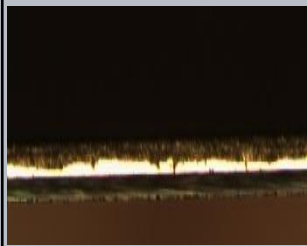
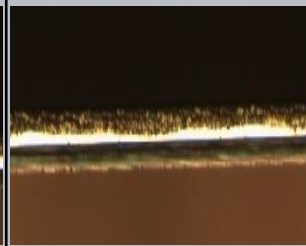
√ Test Parameter

Spindle RPM		Feed Speed	Blade Height	Dicing Blade	Cut Method
Z1	45,000	80 mm/s	155um	ZH05-SD3500-N1-CC	Step Cut
Z2	45,000	80 mm/s	70um	ZH05-SD3500-N1-BB	

√ Test Result

Sample	Wafer Thick.	Corner burr(%)	Side burr(%)	Bleed(%)
ES-229N-20	50um	0.0	2.7	2.7
Competitor A (Model A)	50um	0.0	42.4	36.3

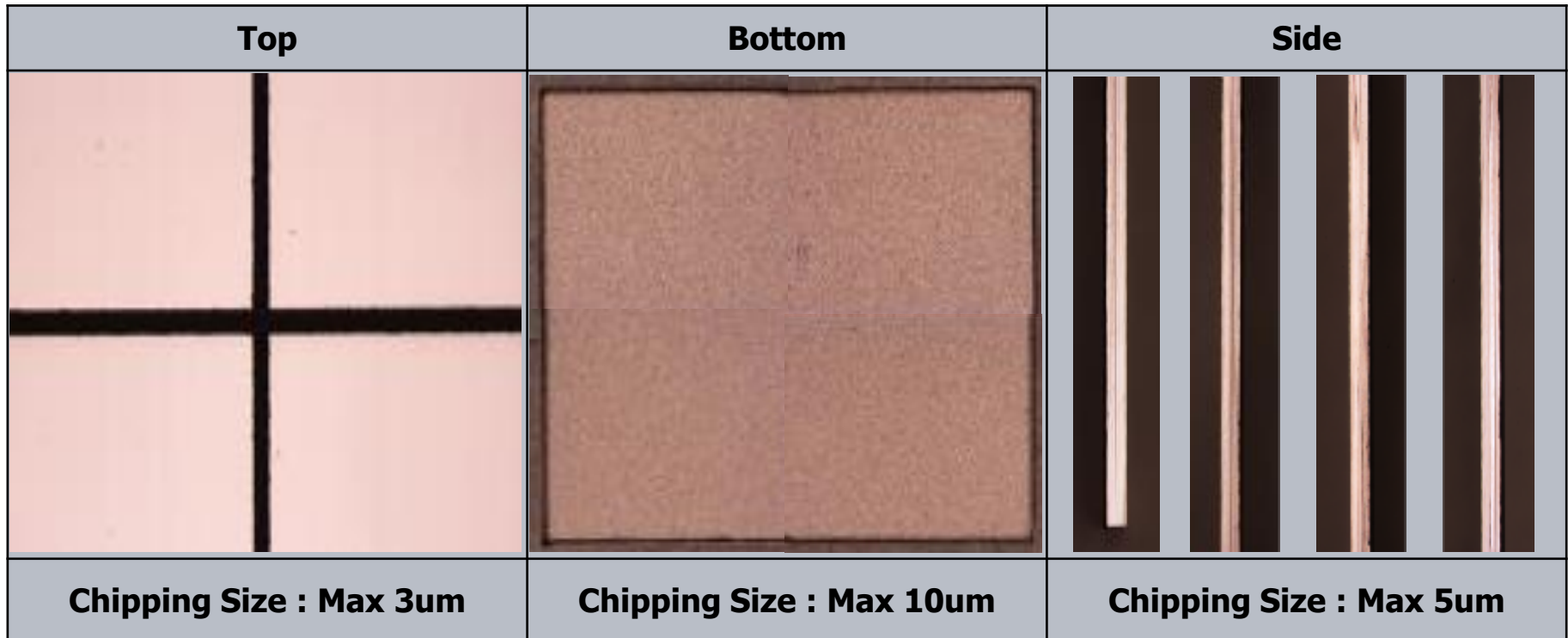
√ Test Image

	Top	Corner	Side	Bleed
ES-229N-20				
Competitor A (Model A)				

Test condition : After UV

√ Back grind / wafer sawing Process Quality Control Data

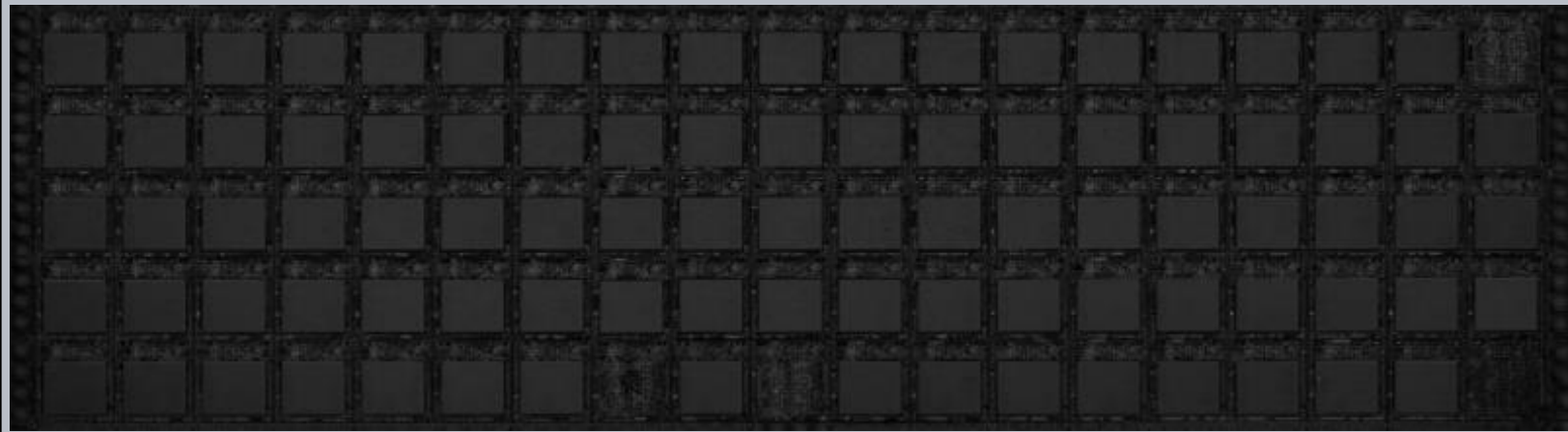
Item	S/S	Spec	1	2	3	4	5	6	7	8	9	10	Min.	Max.	Avg.	Result
Kerf Width	Z1 : 8Line	Max 60um	32	35	32	36	34	35	37	32	32	33	32.0	37.0	33.8	Accept
	Z2 : 8Line		30	32	31	32	31	33	31	35	36	35	30.0	36.0	32.6	Accept



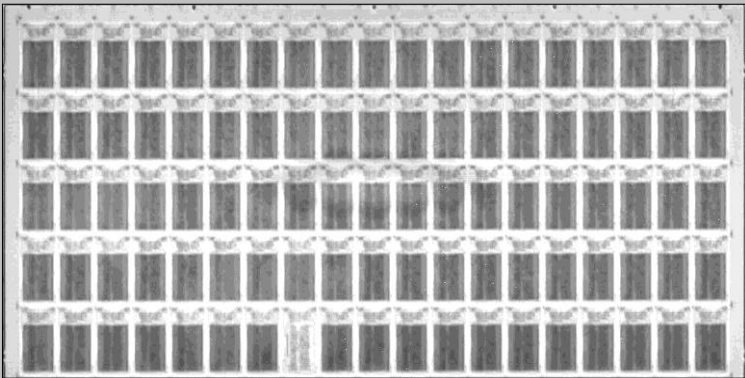
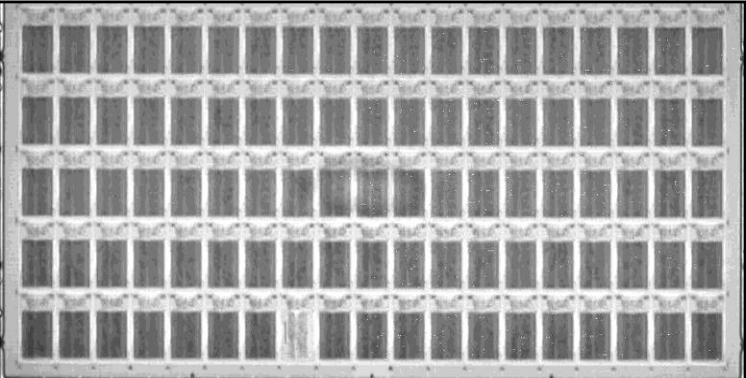
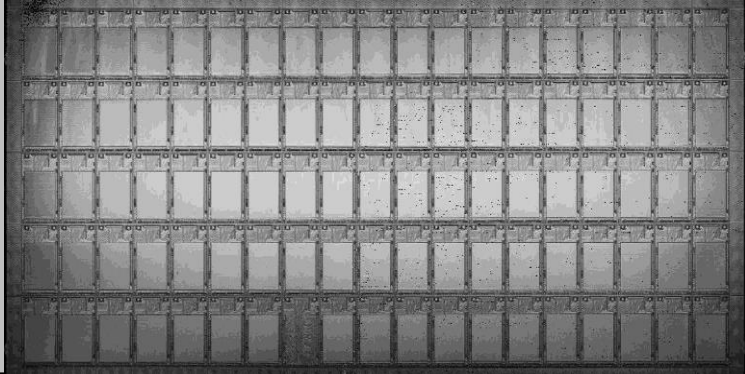
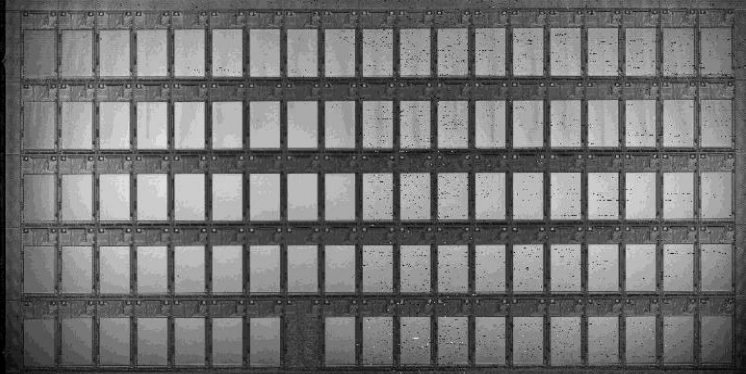
√ Back grind / wafer sawing Process Quality Control Data

Item	Die	S/S	Spec.	1	2	3	4	5	6	7	8	9	10	Min.	Max.	Avg.	Result
Die Position	1st Die	X : 10Unit	± 50um	13	16	18	10	16	11	10	15	13	13	10	18	14	Accept
		Y : 10Unit		8	13	10	13	11	11	13	14	13	12	8	14	12	Accept
	2nd Die	X : 10Unit		11	8	8	10	6	11	10	11	11	13	6	13	10	Accept
		Y : 10Unit		13	11	12	10	11	14	15	17	13	11	10	17	13	Accept

√ Chip to Chip Void

C-Scan	Result
	Accept

✓ Pre-con Test

Condition	Before Pre-con	After Pre-con	Result
85/85 96hrs			Accept
			Accept

T/C	-55~125°C, 5cycle
Bake	125°C 24Hrs
T/H	85°C/85% 96Hrs
Reflow	Peak 260°C, 3 cycle

Thank You!